#### features

- Up to 150-mA Output Current
- Less Than 10-mV<sub>pp</sub> Output Voltage Ripple
- No Inductors Required/Low EMI
- Regulated 5-V ±4% Output
- Only Four External Components Required
- Up to 90% Efficiency
- 2.7-V to 5.4-V Input Voltage Range
- 60-μA Quiescent Supply Current
- 0.05-μA Shutdown Current
- Load Isolated in Shutdown
- Space-Saving Thermally-Enhanced TSSOP PowerPAD™ Package
- Evaluation Module Available (TPS60110EVM-132)

#### description

The TPS60111 step-up, regulated charge pump generates a 5-V  $\pm 4\%$  output voltage from a 2.7-V to 5.4-V input voltage (three alkaline, NiCd, or NiMH batteries; or, one lithium or lithium ion battery). Output current is 150 mA from a 3-V input. Only four external capacitors are needed to build a complete low-noise dc/dc converter. The push-pull operating mode of two single-ended charge pumps assures the low output voltage ripple as current is continuously transferred to the output. From a 3-V input, the TPS60111 can start into full load with loads as low as 33  $\Omega$ .

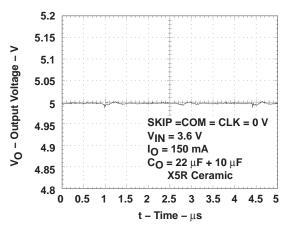
The TPS60111 features either constant frequency mode to minimize noise and output voltage ripple or the power-saving pulse-skip mode to extend battery life at light loads. The TPS60111 switching frequency is 300 kHz. The logic shutdown function reduces the supply current to 1-µA (max) and disconnects the load from the input. Special current-control circuitry prevents excessive current from being drawn from the battery during start-up. This dc/dc converter requires no inductors and has low EMI. It is available in the small 20-pin TSSOP PowerPAD™ package (PWP).

#### applications

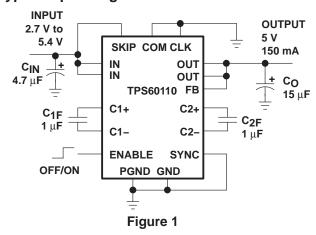
#### Replaces DC/DC Converters With Inductors in

- Battery-Powered Applications
- Li-Ion Battery to 5-V Conversion
- Portable Instruments
- Battery-Powered Microprocessor Systems
- Miniature Equipment
- Backup-Battery Boost Converters
- PDAs
- Laptops
- Handheld Instrumentation
- Medical Instruments

#### output voltage ripple



#### typical operating circuit

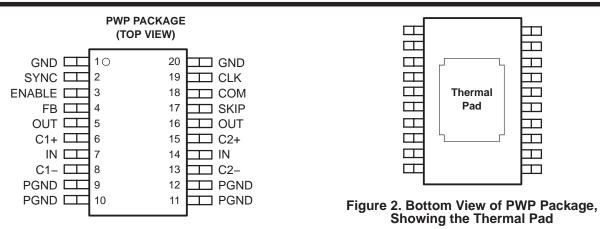




Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

PowerPAD is a trademark of Texas Instruments Incorporated.





#### **AVAILABLE OPTIONS**

PACKAGE
TSSOP <sup>†</sup>
(PWP)
TPS60111PWP

<sup>†</sup> This package is available taped and reeled. To order this packaging option, add an R suffix to the part number (e.g., TPS60111PWPR).

#### **Terminal Functions**

TERMI	NAL		DECODIFICAL CONTRACTOR
NAME	NO.	1/0	DESCRIPTION
CLK	19	I	Input for external clock signal. If the internal clock is used, connect this terminal to GND.
C1+	6		Positive terminal of the charge-pump capacitor C <sub>1F</sub>
C1-	8		Negative terminal of the charge-pump capacitor C <sub>1F</sub>
C2+	15		Positive terminal of the charge-pump capacitor C <sub>2</sub> F
C2-	13		Negative terminal of the charge-pump capacitor C <sub>2</sub> F
СОМ	18	I	Mode selection.  When COM is logic low the charge pump operates in push-pull mode to minimize output ripple. When COM is connected to IN the regulator operates in single-ended mode requiring only one flying capacitor.
ENABLE	3	I	ENABLE Input. The device turns off, the output disconnects from the input, and the supply current decreases to 0.05 $\mu$ A when ENABLE is a logic low. ENABLE high may only be applied when VIN is inside the recommended operating range.
FB	4	I	FEEDBACK input. Connect FB to OUT as close to the load as possible to achieve best regulation. Resistive divider is on-chip to match internal reference voltage of 1.22 V.
GND	1, 20		GROUND. Analog ground for internal reference and control circuitry. Connect to PGND through a short trace.
IN	7, 14	I	Supply Input. Connect to an input supply in the 2.7-V to 5.4-V range. Bypass IN to GND with a $(C_O/2)$ $\mu$ F capacitor. Connect both INs through a short trace.
OUT	5, 16	0	Regulated 5-V power output. Connect both OUTs through a short trace and bypass OUT to GND with the output filter capacitor $C_{O}$ .
PGND	9–12		PGND power ground. Charge-pump current flows through this pin. Connect all PGNDs together.
SKIP	17	I	Mode selection. When SKIP is logic low the charge pump operates in constant-frequency mode. Thus output ripple and noise are minimized. When SKIP is connected to IN, the regulator operates in low-quiescent-current pulse-skip mode.
SYNC	2	I	Selection for external clock signal. Connect to GND to use the internally generated clock signal. Connect to IN for external synchronization. In this case, the clock signal needs to be fed through CLK.



## absolute maximum ratings (unless otherwise noted)†‡

Input voltage range, V <sub>I</sub> (IN, OUT, ENABLE, SKIP, C	COM, CLK, FB, SYNC)
Differential input voltage, V <sub>ID</sub> (C1+, C2+ to GND)	$-0.3 \text{ V to } (\text{V}_{\text{O}} + 0.3 \text{ V})$
Differential input voltage, V <sub>ID</sub> (C1-, C2- to GND)	0.3 V to (V <sub>IN</sub> + 0.3 V)
Continuous total power dissipation	See Dissipation Rating Tables
Continuous output current	200 mA
Storage temperature range, T <sub>stq</sub>	–55°C to 150°C
Lead temperature 1,6 mm (1/16 inch) from case for	<sup>-</sup> 10s
Maximum junction temperature, T.J	150°C

<sup>†</sup> Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

#### DISSIPATION RATING TABLE 1 - FREE-AIR TEMPERATURE (see Figure 3)

PACKAGE	$T_{\mbox{A}} \le 25^{\circ}\mbox{C}$ POWER RATING	DERATING FACTOR ABOVE T <sub>A</sub> = 25°C	T <sub>A</sub> = 70°C POWER RATING	T <sub>A</sub> = 85°C POWER RATING
PWP	700 mW	5.6 mW/°C	448 mW	364 mW

#### DISSIPATION RATING TABLE 2 - CASE TEMPERATURE (see Figure 4)

PACKAGE	T <sub>C</sub> ≤ 62.5°C	DERATING FACTOR	T <sub>C</sub> = 70°C	T <sub>C</sub> = 85°C
	POWER RATING	ABOVE T <sub>C</sub> = 62.5°C	POWER RATING	POWER RATING
PWP	25 W	285.7 mW/°C	22.9 W	18.5 W

#### **DISSIPATION DERATING CURVE§**

## FREE-AIR TEMPERATURE 1400 $P_{ m D}$ – Maximum Continuous Dissipation – mW 1200 1000 800 600 **PWP Package** R<sub>θ</sub>J<sub>A</sub> = 178°C/W 400 200 0 25 150 TA - Free-Air Temperature - °C

Figure 3

#### MAXIMUM CONTINUOUS DISSIPATION§ vs

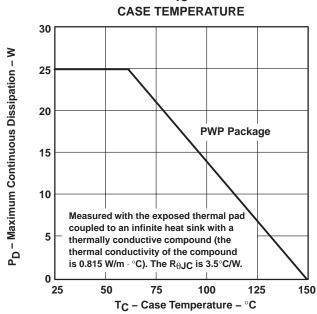


Figure 4



VENABLE, VSKIP, VCOM, VCLK and VSYNC can exceed VIN up to the maximum rated voltage without increasing the leakage current drawn by these mode select inputs.

<sup>§</sup> Dissipation rating tables and figures are provided for maintenance of junction temperature at or below absolute maximum temperature of 150°C. It is recommended not to exceed a junction temperature of 125°C.

## **TPS60111 REGULATED 5-V 150-mA LOW-NOISE** CHARGE PUMP DC/DC CONVERTER SLVS216B – JUNE 1999 – JUNE 2008

# electrical characteristics at C<sub>IN</sub> = 15 $\mu$ F, C<sub>1F</sub> = C<sub>2F</sub> = 2.2 $\mu$ F<sup>†</sup>, C<sub>O</sub> = 33 $\mu$ F, T<sub>C</sub> = -40°C to 85°C, V<sub>IN</sub> = 3 V, V<sub>FB</sub> = V<sub>O</sub>, V<sub>ENABLE</sub> = V<sub>IN</sub>, V<sub>SKIP</sub> = V<sub>IN</sub> or 0 V and V<sub>COM</sub> = V<sub>CLK</sub> = V<sub>SYNC</sub> = 0 V (unless otherwise noted)

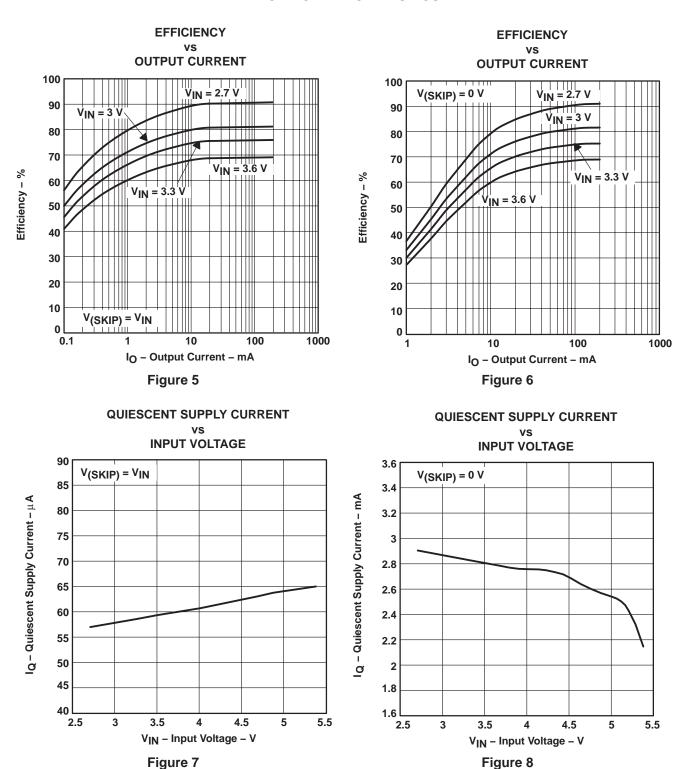
	PARAMETER	TEST CO	ONDITIONS	MIN	TYP	MAX	UNIT	
V <sub>IN</sub>	Input voltage			2.7		5.4	V	
IO(MAX)	Maximum output current			150			mA	
		2.7 V < V <sub>IN</sub> < 3 V, V <sub>O</sub> (Start-Up) = 5 V,	$0 < I_O < 75 \text{ mA},$ $T_C = 25^{\circ}\text{C}$	4.8	5	5.2		
VO	Output voltage	3 V < V <sub>IN</sub> < 5 V,	0 < I <sub>O</sub> < 150 mA	4.8	5	5.2	V	
		5 V < V <sub>IN</sub> < 5.4 V,	0 < I <sub>O</sub> < 150 mA	4.8	5	5.25		
VO(RIP)	Output voltage ripple	I <sub>O</sub> = 150 mA,	V <sub>SKIP</sub> = 0 V		10‡		mVpp	
lO(LEAK)	Output leakage current	V <sub>IN</sub> = 3.6 V,	VENABLE = 0 V			1	μΑ	
	Quiescent current	V <sub>SKIP</sub> = V <sub>IN</sub> = 3.6 V			60	90	μΑ	
lQ	(no-load input current)	V <sub>SKIP</sub> = 0 V,	V <sub>IN</sub> = 3.6 V		2.8		mA	
IDD(SDN)	Shutdown supply current	V <sub>IN</sub> = 3.6 V,	V <sub>ENABLE</sub> = 0 V		0.05	1	μΑ	
fOSC(int)	Internal switching frequency	V <sub>IN</sub> = 3.6 V		200	300	400	kHz	
fOSC(ext)	External clock frequency	VSYNC = VIN,	$V_{IN} = 2.7 \text{ V to } 5.4 \text{ V}$	400	600	800	kHz	
	External clock duty cycle	V <sub>SYNC</sub> = V <sub>IN</sub> ,	V <sub>IN</sub> = 2.7V to 5.4 V	20%		80%		
	Efficiency	I <sub>O</sub> = 75 mA			80%			
V <sub>INL</sub>	Input voltage low, ENABLE, SKIP, COM, CLK, SYNC	V <sub>IN</sub> = 2.7 V				0.3 × V <sub>IN</sub>	V	
VINH	Input voltage high, ENABLE, SKIP, COM, CLK, SYNC	V <sub>IN</sub> = 5.4 V		0.7 × V <sub>IN</sub>			V	
I <sub>I(LEAK)</sub>	Input leakage current, ENABLE, SKIP, COM, CLK, SYNC	VENABLE = VSKIP = VSYNC = VGND or V			0.01	0.1	μΑ	
	Output load regulation	$V_{O} = 5 \text{ V},$ $T_{C} = 25^{\circ}\text{C}$	1 mA < I <sub>O</sub> < 150 mA		0.002		%/mA	
	Output line regulation	3 V < V <sub>IN</sub> < 5 V, I <sub>O</sub> = 75 mA,	$V_{O} = 5 V,$ $T_{C} = 25^{\circ}C$		0.6		%/V	
	Short circuit current	V <sub>IN</sub> = 3.6 V T <sub>C</sub> = 25°C	V <sub>O</sub> = 0 V,		150		mA	

<sup>†</sup> Use only ceramic capacitors with X5R or X7R dielectric as flying capacitors.



<sup>‡</sup> Achieved with  $C_O = 22 \mu F + 10 \mu F X5R$  dielectric ceramic capacitor

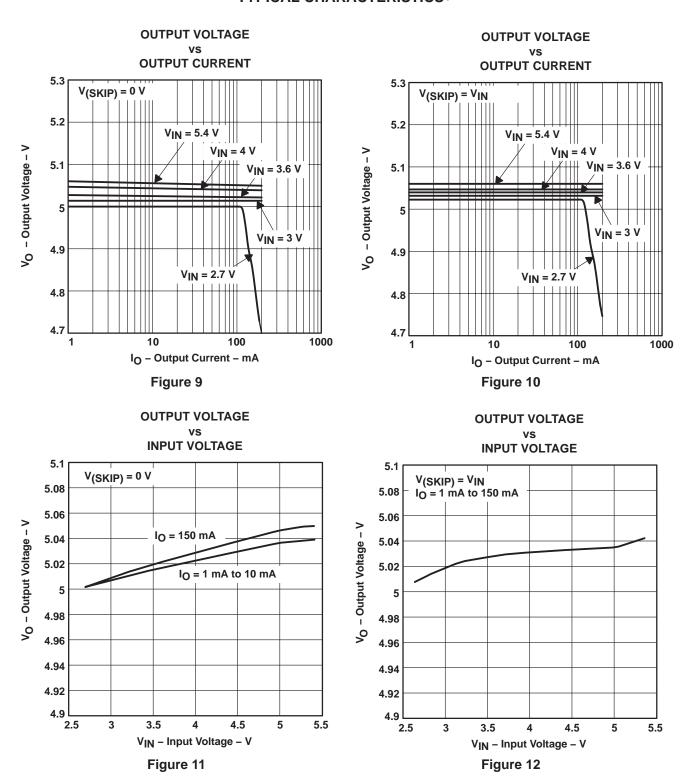
#### TYPICAL CHARACTERISTICS<sup>†</sup>



 $\dagger T_{C} = 25^{\circ}C, \ V_{COM} = V_{SYNC} = 0 \ V, \ C_{IN} = 15 \ \mu\text{F}, \ C_{1F} \ \text{and} \ C_{2F} = 2.2 \ \mu\text{F} \ (\text{X7R ceramic}), \ C_{O} = 33 \ \mu\text{F}, \ \text{unless otherwise noted}$ 



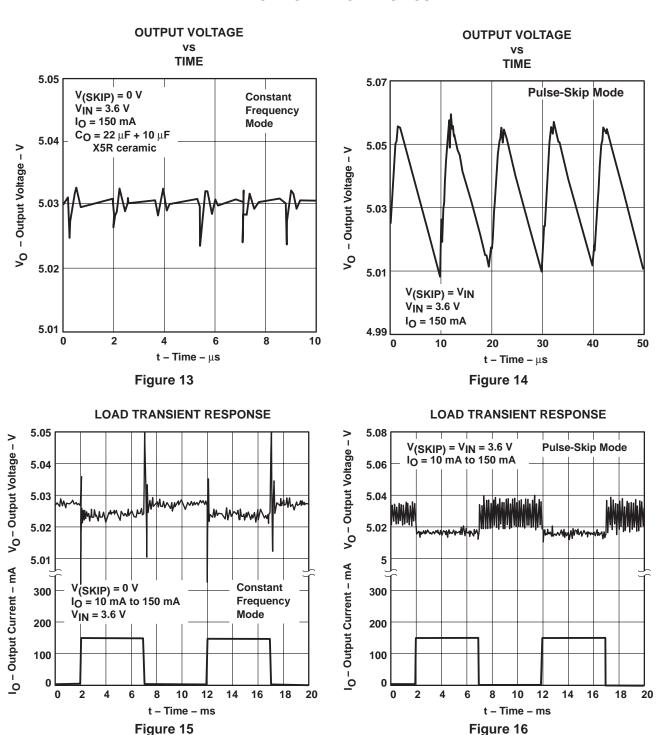
#### TYPICAL CHARACTERISTICS<sup>†</sup>



 $+T_C = 25^{\circ}C$ ,  $V_{COM} = V_{SYNC} = 0$  V,  $C_{IN} = 15$   $\mu$ F,  $C_{1F}$  and  $C_{2F} = 2.2$   $\mu$ F (X7R ceramic),  $C_{O} = 33$   $\mu$ F, unless otherwise noted



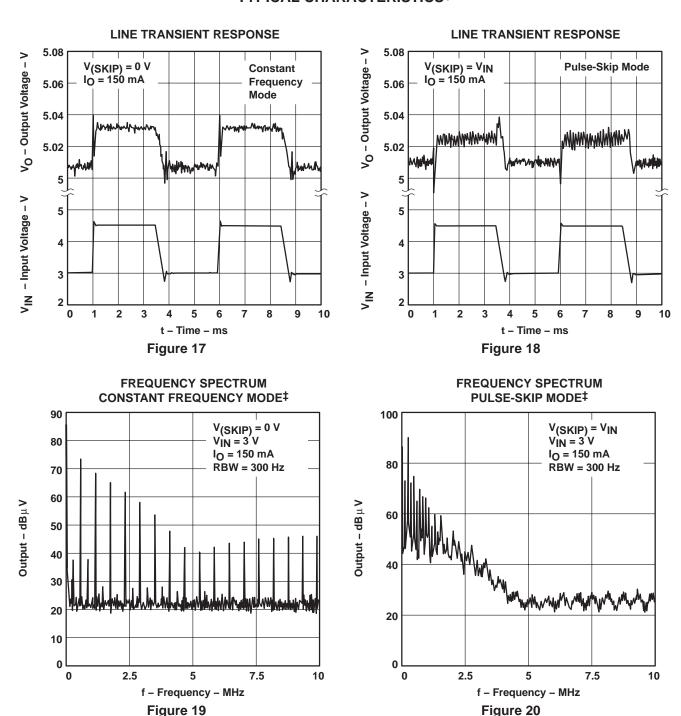
#### TYPICAL CHARACTERISTICS<sup>†</sup>



 $\dagger$  T<sub>C</sub> = 25°C, V<sub>COM</sub> = V<sub>SYNC</sub> = 0 V, C<sub>IN</sub> = 15  $\mu$ F, C<sub>1</sub>F and C<sub>2</sub>F = 2.2  $\mu$ F (X7R ceramic), C<sub>O</sub> = 33  $\mu$ F, unless otherwise noted



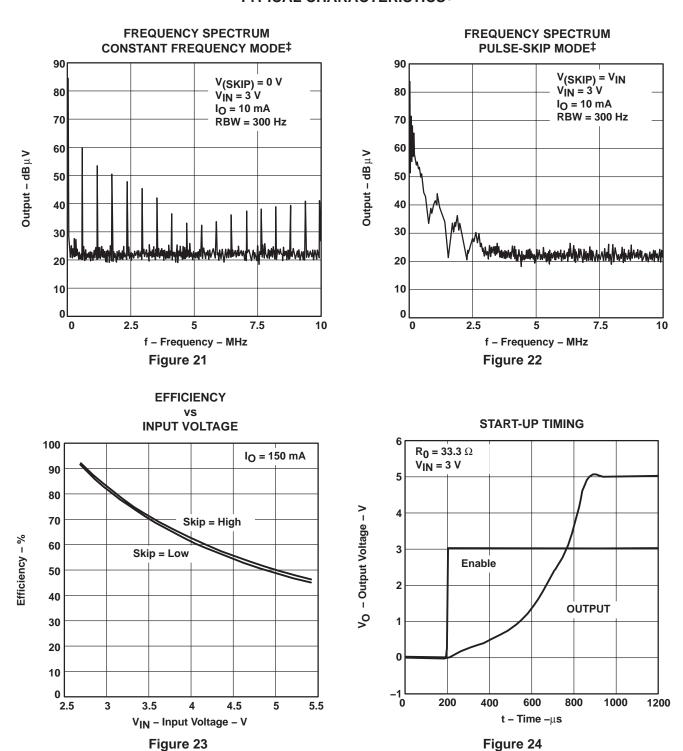
#### TYPICAL CHARACTERISTICS<sup>†</sup>



 $^+T_C$  = 25°C,  $V_{COM}$  =  $V_{SYNC}$  = 0 V,  $C_{IN}$  = 15  $\mu$ F,  $C_{1F}$  and  $C_{2F}$  = 2.2  $\mu$ F (X7R ceramic),  $C_O$  = 33  $\mu$ F, unless otherwise noted  $^+T_{COM}$  = 15  $^+T$ 



#### TYPICAL CHARACTERISTICS<sup>†</sup>



 $^+$ TC = 25°C, VCOM = VSYNC = 0 V, CIN = 15  $\mu$ F, C1F and C2F = 2.2  $\mu$ F (X7R ceramic), CO = 33  $\mu$ F, unless otherwise noted  $^+$ Test circuit: TPS60110EVM-132 with TPS60111



#### detailed description

#### operating principle

The TPS60111 charge pump provides a regulated 5-V output from a 2.7-V to 5.4-V input. It delivers a maximum load current of 150 mA. Designed specifically for space critical battery powered applications, the complete charge pump circuit requires only four external capacitors. The circuit can be optimized for highest efficiency at light loads or lowest output noise. The TPS60111 consists of an oscillator, a 1.22-V bandgap reference, an internal resistive feedback circuit, an error amplifier, high current MOSFET switches, a shutdown/start-up circuit, and a control circuit (Figure 25).

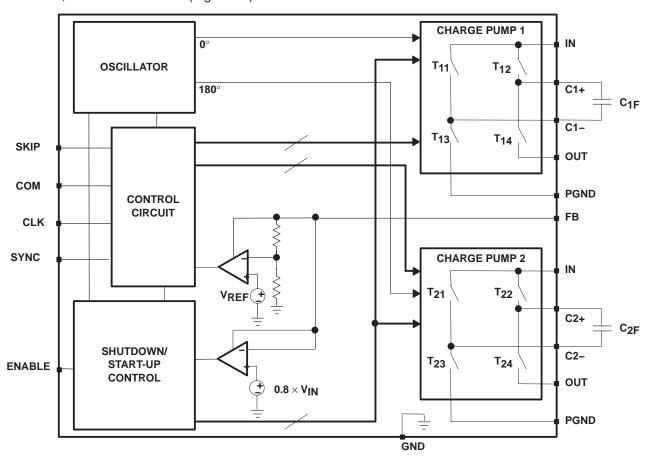


Figure 25. Functional Block Diagram TPS60111

The oscillator runs at a 50% duty cycle. The device consists of two single-ended charge pumps which operate with 180° phase shift. Each single ended charge pump transfers charge into its transfer capacitor ( $C_{XF}$ ) in one half of the period. During the other half of the period (transfer phase),  $C_{XF}$  is placed in series with the input to transfer its charge to  $C_O$ . While one single-ended charge pump is in the charge phase, the other one is in the transfer phase. This operation guarantees an almost constant output current which ensures a low output ripple.

If the clock were to run continuously, this process would eventually generate an output voltage equal to two times the input voltage (hence the name doubler). In order to provide a regulated fixed output voltage of 5 V, the TPS60111 uses either pulse-skip mode or constant-frequency mode. Pulse-skip mode and constant-frequency mode are externally selected via the SKIP input pin.



#### detailed description (continued)

#### start-up procedure

During start-up, i.e. when ENABLE is set from logic low to logic high, the switches T12 and T14 (charge pump 1), and the switches T22 and T24 (charge pump 2) are conducting to charge up the output capacitor until the output voltage  $V_O$  reaches  $0.8\times V_{IN}$ . When the start-up comparator detects this limit, the IC begins to operate in the mode selected with SKIP and COM. This start-up charging of the output capacitor guarantees a short start-up time and eliminates the need for a Schottky diode between IN and OUT.

#### pulse-skip mode

In pulse-skip mode (SKIP = high), the error amplifier disables switching of the power stages when it detects an output higher than 5 V. The oscillator halts. The IC then skips switching cycles until the output voltage drops below 5 V. Then the error amplifier reactivates the oscillator and switching of the power stages starts again. The pulse-skip regulation mode minimizes operating current because it does not switch continuously and deactivates all functions except bandgap reference and error amplifier when the output is higher than 5 V. When switching is disabled from the error amplifier, the load is also isolated from the input. SKIP is a logic input and should not remain floating. The typical operating circuit of the TPS60111 in pulse skip mode is shown in Figure 1.

#### constant-frequency mode

When SKIP is low, the charge pump runs continuously at the frequency  $f_{OSC}$ . The control circuit, fed from the error amplifier, controls the charge on  $C_{1F}$  and  $C_{2F}$  by driving the gates of the FETs  $T_{12}/T_{13}$  and  $T_{22}/T_{23}$ , respectively. When the output voltage falls, the gate drive increases, resulting in a larger voltage across  $C_{1F}$  and  $C_{2F}$ . This regulation scheme minimizes output ripple. Since the device switches continuously, the output noise contains well-defined frequency components, and the circuit requires smaller external capacitors for a given output ripple. However, constant-frequency mode, due to higher operating current, is less efficient at light loads than pulse-skip mode.

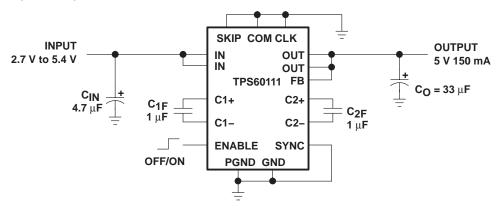


Figure 26. Typical Operating Circuit TPS60111 in Constant Frequency Mode

Table 1. Tradeoffs Between Operating Modes

FEATURE	PULSE-SKIP MODE (SKIP = High)	CONSTANT-FREQUENCY MODE (SKIP = Low)
Best light-load efficiency	X	
Smallest external component size for a given output ripple		X
Output ripple amplitude	Small amplitude	Very small amplitude
Output ripple frequency	Variable	Constant
Load regulation	Very good	Good

NOTE: Even in pulse-skip mode the output ripple amplitude is small if the push-pull operating mode is selected via COM.



#### detailed description (continued)

#### push-pull operating mode

In push-pull operating mode (COM = low), the two single-ended charge pumps operate with 180° phase shift. The oscillator signal has a 50% duty cycle. Each single-ended charge pump transfers charge into its transfer capacitor (C<sub>xF</sub>) in one-half of the period. During the other half of the period (transfer phase), C<sub>xF</sub> is placed in series with the input to transfer its charge to CO. While one single-ended charge pump is in the charge phase, the other one is in the transfer phase. This operation guarantees an almost constant output current which ensures a low output ripple. COM is a logic input and should not remain floating. The typical operating circuit of the TPS60111 in push-pull mode is shown in Figure 1 and Figure 26.

#### single-ended operating mode

When COM is high, the device runs in single-ended operating mode. The two single-ended charge pumps operate in parallel without phase shift. They transfer charge into the transfer capacitor (C<sub>F</sub>) in one half of the period. During the other half of the period (transfer phase), CF is placed in series with the input to transfer its charge to  $C_O$ . In single-ended operating mode only one transfer capacitor ( $C_F = C_{1F} + C_{2F}$ ) is required, resulting in less board space.

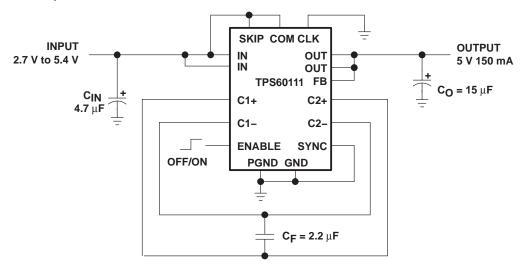


Figure 27. Typical Operating Circuit TPS60111 in Single-Ended Operating Mode

**Table 2. Tradeoffs Between Operating Modes** 

FEATURE	PUSH-PULL MODE (COM = Low)	SINGLE-ENDED MODE (COM = High)
Output ripple amplitude	Small amplitude	Large amplitude
Smallest board space		X



#### detailed description (continued)

#### shutdown

Driving ENABLE low places the device in shutdown mode. This disables all switches, the oscillator, and control logic. The device typically draws 0.05- $\mu$ A (1- $\mu$ A max) of supply current in this mode. Leakage current drawn from the output is as low as 1  $\mu$ A max. The device exits shutdown once ENABLE is set high level. The typical no-load shutdown exit time is 20  $\mu$ s. When the device is in shutdown, the load is isolated from the input and the output is high impedance.

#### external clock signal

If the device operates at a user-defined frequency, an external clock signal can be used. Therefore, SYNC needs to be connected to IN and the external oscillator signal can drive CLK. The maximum external frequency is limited to 800 kHz. The switching frequency of the converter is half of the external oscillator frequency. It is recommended to operate the charge pump in constant-frequency mode if an external clock signal is used so that the output noise contains only well-defined frequency components.

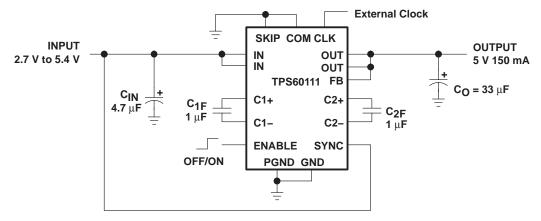


Figure 28. Typical Operating Circuit TPS60111 With External Synchronization



#### APPLICATION INFORMATION

#### capacitor selection

The TPS60111 requires only four external capacitors as shown in the basic application circuit. Their values are closely linked to the output current capacity, output noise requirements, and mode of operation. Generally, the transfer capacitors ( $C_{xF}$ ) will be the smallest.

The input capacitor improves system efficiency by reducing the input impedance and stabilizes the input current.  $C_{IN}$  is recommended to be about two to four times as large as  $C_{xF}$ .

The output capacitor  $(C_O)$  can be selected from 8-times to 50-times larger than  $C_{\chi F}$ , depending on the mode of operation and ripple tolerance<sup>†</sup>. Tables 3 and 4 show capacitor values recommended for low quiescent-current operation (pulse-skip mode) and for low output voltage ripple operation (constant-frequency mode). A recommendation is given for smallest size.

Table 3. Recommended Capacitor Values for Low Quiescent-Current Operation<sup>†</sup> (pulse-skip mode)

V <sub>IN</sub>	IO [mA]	C <sub>IN</sub> [µF]		C <sub>xF</sub>		<b>ο</b> μ <b>F</b> ]	OUTPUT VOLTAGE
[V]		TANTALUM	CERAMIC	[μ <b>F</b> ]	TANTALUM	CERAMIC	RIPPLE V <sub>PP</sub> [mV]
3.6	75	4.7		1	15		150
3.6	75		4.7 (X7R)	1		10 (X5R)	105
3.6	150	4.7		1	15		150
3.6	150		4.7 (X7R)	1		10 (X5R)	105

<sup>†</sup> All measurements are done with additional 1-μF X7R ceramic capacitors at input and output.

Table 4. Recommended Capacitor Values for Low Output Voltage Ripple Operation<sup>†</sup> (constant-frequency mode)

VIN	I <sub>O</sub>	С <sub>IN</sub> [µF]		C <sub>xF</sub> [μ <b>F</b> ]	[	C <sub>O</sub> μ <b>F</b> ]	OUTPUT VOLTAGE
[V]	[mA]	TANTALUM	CERAMIC	լμεյ	TANTALUM	CERAMIC	RIPPLE V <sub>PP</sub> [mV]
3.6	75	4.7		1	33		10
3.6	75		4.7 (X7R)	1		22 + 10, (X5R)	6
3.6	150	4.7		1	33		17
3.6	150		4.7 (X7R)	1		22 + 10, (X5R)	10

<sup>†</sup>All measurements are done with additional 1-µF X7R ceramic capacitors at input and output.



#### APPLICATION INFORMATION

For the TPS60111, the smallest board space size can be achieved using Sprague's 595D-series tantalum capacitors for input and output. However, with the trend towards high capacitance ceramic capacitors in smaller size packages, these type of capacitors might soon become competitive in size.

**MANUFACTURER PART NUMBER** CAPACITANCE **TYPE** Ceramic Taiyo Yuden LMK212BJ105KG-T  $1 \mu F$ LMK212BJ225MG-T  $2.2 \mu F$ Ceramic LMK316BJ475KL-T  $4.7 \mu F$ Ceramic Ceramic JMK316BJ106ML-T 10 μF LMK432BJ226MM-T 22 μF Ceramic AVX 0805ZC105KAT2A  $1 \mu F$ Ceramic 12067C225KAT2A  $2.2 \, \mu F$ Ceramic  $4.7 \mu F$ TPSC475K035R0600 **Tantalum** TPSC156K020R0450 15 μF Tantalum TPSC336K010R0375  $33 \mu F$ **Tantalum** 595D475X0016A2T  $4.7 \mu F$ Tantalum Sprague 595D156X06R3A2T 15 μF Tantalum 595D156X0016B2T 15 μF **Tantalum** 595D336X06R3A2T  $33 \, \mu F$ **Tantalum** 595D336X0016B2T  $33 \mu F$ **Tantalum** 595D336X0016C2T 33 µF **Tantalum** Kemet T494B475M010AS 4.7 μF Tantalum T494C156K010AS 15 μF **Tantalum** T494C336K010AS  $33 \mu F$ Tantalum

**Table 5. Recommended Capacitors** 

Table 6 lists the manufacturers of recommended capacitors. In most applications surface-mount tantalum capacitors will be the right choice. However, ceramic capacitors will provide the lowest output voltage ripple due to their typically lower ESR.

MANUFACTURER CAPACITOR TYPE INTERNET
Taiyo Yuden X7R/X5R ceramic www.t-yuden.com

**Table 6. Recommended Capacitor Manufacturers** 

AVX	X7R/X5R ceramic TPS–series tantalum	www.avxcorp.com
Sprague	595D-series tantalum 593D-series tantalum	www.vishay.com
Kemet	T494-series tantalum	www.kemet.com

#### power dissipation

The power dissipated in the TPS60111 depends on output current and is approximated by:

$$P_{DISS} = I_{O} \times (2 V_{IN} - V_{O}) \text{ for } I_{Q} < < I_{O}$$

P<sub>DISS</sub> must be less than that allowed by the package rating. See the ratings for 20-PowerPAD™ package power-dissipation limits and deratings.



#### **APPLICATION INFORMATION**

#### layout

All capacitors should be soldered in close proximity to the IC. A PCB layout proposal for a two-layer board is given in Figure 29. Care has been taken to connect both single-ended charge pumps symmetrically to the load to achive optimized output voltage ripple performance. The proposed layout also provides improved thermal performance as the exposed leadframe is soldered to the PCB. The bottom layer of the PCB is a ground plain only. All ground areas on the PCB should be connected. Connect ground areas on top layer to the bottom layer via through hole connections.

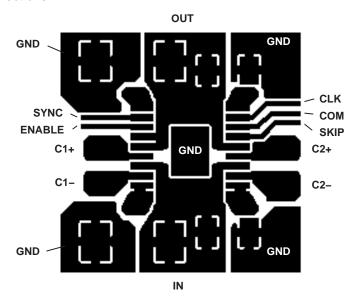


Figure 29. Recommended PCB Layout for TPS60111 (top view)

The evaluation module designed for the TPS60110 can, with slight modifications, be used for evaluation of the TPS60111. The EVM can be ordered under literature code SLVP132 or under product code TPS60110EVM-132.



#### **APPLICATION INFORMATION**

#### applications proposals

#### TPS60111 with LC output filter for ultra low ripple

For applications where extremely low output ripple is required, a small LC filter is recommended. This is shown in Figure 30. The addition of a small inductor and filter capacitor will reduce the output ripple well below what could be achieved with capacitors alone. The corner frequency of 500 kHz was chosen above the 300 kHz switching frequency to avoid loop stability issues in case the feedback is taken from the output of the LC filter. Leaving the feedback (FB) connection point before the LC filter, the filter capacitance value can be increased to achieve even higher ripple attenuation without affecting stability margin.

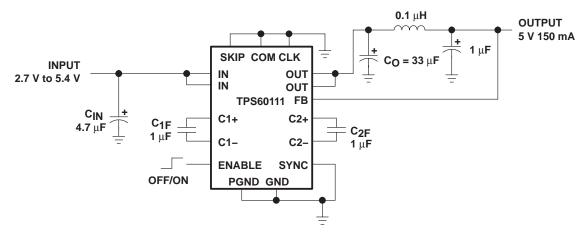


Figure 30. TPS60111 With LC Filter for Ultra Low Output Ripple Applications

#### related information

#### application reports

For more application information see:

- PowerPAD™ Application Report (Literature Number: SLMA002)
- TPS6010x/TPS6011x Charge Pump Application Report (Literature Number: SLVA070)

#### device family products

Other devices in this family are:

PART NUMBER	LITERATURE NUMBER	DESCRIPTION
TPS60100	SLVS213	Regulated 3.3-V, 200-mA Low-Noise Charge Pump DC/DC Converter
TPS60101	SLVS214	Regulated 3.3-V, 100-mA Low-Noise Charge Pump DC/DC Converter
TPS60110	SLVS215	Regulated 5-V, 300-mA Low-Noise Charge Pump DC/DC Converter





#### PACKAGE OPTION ADDENDUM

10-Jun-2014

#### PACKAGING INFORMATION

www.ti.com

Orderable Device	Status	Package Type	_	Pins	Package	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking	Samples
	(1)		Drawing		Qty	(2)	(6)	(3)		(4/5)	
TPS60111PWP	ACTIVE	HTSSOP	PWP	20	70	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 85	TPS60111	Samples
TPS60111PWPG4	ACTIVE	HTSSOP	PWP	20	70	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 85	TPS60111	Samples
TPS60111PWPR	ACTIVE	HTSSOP	PWP	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 85	TPS60111	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

**Pb-Free (RoHS):** TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

**Pb-Free (RoHS Exempt):** This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead/Ball Finish Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and



### **PACKAGE OPTION ADDENDUM**

10-Jun-2014

continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

## PACKAGE MATERIALS INFORMATION

www.ti.com 26-Jan-2013

#### TAPE AND REEL INFORMATION





	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

#### QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



#### \*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TPS60111PWPR	HTSSOP	PWP	20	2000	330.0	16.4	6.95	7.1	1.6	8.0	16.0	Q1

**PACKAGE MATERIALS INFORMATION** 

www.ti.com 26-Jan-2013



#### \*All dimensions are nominal

ĺ	Device Package Type		Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)	
	TPS60111PWPR	HTSSOP	PWP	20	2000	367.0	367.0	38.0	

PWP (R-PDSO-G20)

## PowerPAD™ PLASTIC SMALL OUTLINE



NOTES:

- All linear dimensions are in millimeters.
- This drawing is subject to change without notice.
- Body dimensions do not include mold flash or protrusions. Mold flash and protrusion shall not exceed 0.15 per side.
- This package is designed to be soldered to a thermal pad on the board. Refer to Technical Brief, PowerPad Thermally Enhanced Package, Texas Instruments Literature No. SLMA002 for information regarding recommended board layout. This document is available at www.ti.com <a href="http://www.ti.com">http://www.ti.com</a>.

  E. See the additional figure in the Product Data Sheet for details regarding the exposed thermal pad features and dimensions.
- E. Falls within JEDEC MO-153

PowerPAD is a trademark of Texas Instruments.



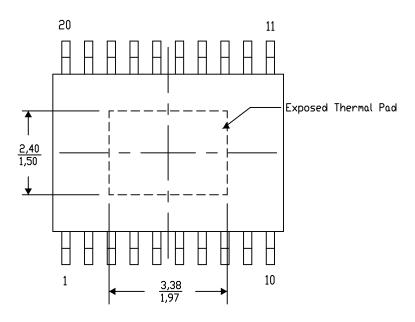
# PWP (R-PDSO-G20) PowerPAD™ SMALL PLASTIC OUTLINE

#### THERMAL INFORMATION

This PowerPAD<sup>TM</sup> package incorporates an exposed thermal pad that is designed to be attached to a printed circuit board (PCB). The thermal pad must be soldered directly to the PCB. After soldering, the PCB can be used as a heatsink. In addition, through the use of thermal vias, the thermal pad can be attached directly to the appropriate copper plane shown in the electrical schematic for the device, or alternatively, can be attached to a special heatsink structure designed into the PCB. This design optimizes the heat transfer from the integrated circuit (IC).

For additional information on the PowerPAD package and how to take advantage of its heat dissipating abilities, refer to Technical Brief, PowerPAD Thermally Enhanced Package, Texas Instruments Literature No. SLMA002 and Application Brief, PowerPAD Made Easy, Texas Instruments Literature No. SLMA004. Both documents are available at www.ti.com.

The exposed thermal pad dimensions for this package are shown in the following illustration.



Top View

Exposed Thermal Pad Dimensions

4206332-19/AO 01/16

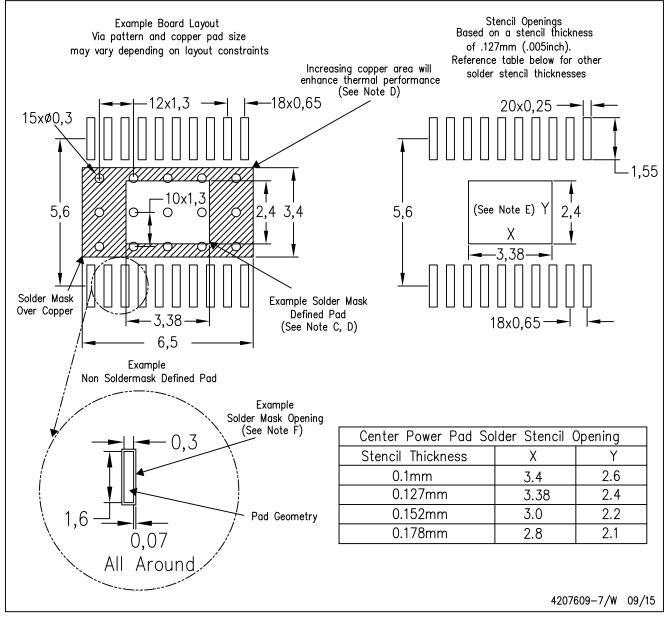
NOTE: A. All linear dimensions are in millimeters

PowerPAD is a trademark of Texas Instruments



## PWP (R-PDSO-G20)

## PowerPAD™ PLASTIC SMALL OUTLINE



#### NOTES:

- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Customers should place a note on the circuit board fabrication drawing not to alter the center solder mask defined pad.
- D. This package is designed to be soldered to a thermal pad on the board. Refer to Technical Brief, PowerPad Thermally Enhanced Package, Texas Instruments Literature No. SLMA002, SLMA004, and also the Product Data Sheets for specific thermal information, via requirements, and recommended board layout. These documents are available at www.ti.com <a href="http://www.ti.com">http://www.ti.com</a>. Publication IPC-7351 is recommended for alternate designs.
- E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Example stencil design based on a 50% volumetric metal load solder paste. Refer to IPC-7525 for other stencil recommendations.
- F. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



#### IMPORTANT NOTICE

Texas Instruments Incorporated and its subsidiaries (TI) reserve the right to make corrections, enhancements, improvements and other changes to its semiconductor products and services per JESD46, latest issue, and to discontinue any product or service per JESD48, latest issue. Buyers should obtain the latest relevant information before placing orders and should verify that such information is current and complete. All semiconductor products (also referred to herein as "components") are sold subject to TI's terms and conditions of sale supplied at the time of order acknowledgment.

TI warrants performance of its components to the specifications applicable at the time of sale, in accordance with the warranty in TI's terms and conditions of sale of semiconductor products. Testing and other quality control techniques are used to the extent TI deems necessary to support this warranty. Except where mandated by applicable law, testing of all parameters of each component is not necessarily performed.

TI assumes no liability for applications assistance or the design of Buyers' products. Buyers are responsible for their products and applications using TI components. To minimize the risks associated with Buyers' products and applications, Buyers should provide adequate design and operating safeguards.

TI does not warrant or represent that any license, either express or implied, is granted under any patent right, copyright, mask work right, or other intellectual property right relating to any combination, machine, or process in which TI components or services are used. Information published by TI regarding third-party products or services does not constitute a license to use such products or services or a warranty or endorsement thereof. Use of such information may require a license from a third party under the patents or other intellectual property of the third party, or a license from TI under the patents or other intellectual property of TI.

Reproduction of significant portions of TI information in TI data books or data sheets is permissible only if reproduction is without alteration and is accompanied by all associated warranties, conditions, limitations, and notices. TI is not responsible or liable for such altered documentation. Information of third parties may be subject to additional restrictions.

Resale of TI components or services with statements different from or beyond the parameters stated by TI for that component or service voids all express and any implied warranties for the associated TI component or service and is an unfair and deceptive business practice. TI is not responsible or liable for any such statements.

Buyer acknowledges and agrees that it is solely responsible for compliance with all legal, regulatory and safety-related requirements concerning its products, and any use of TI components in its applications, notwithstanding any applications-related information or support that may be provided by TI. Buyer represents and agrees that it has all the necessary expertise to create and implement safeguards which anticipate dangerous consequences of failures, monitor failures and their consequences, lessen the likelihood of failures that might cause harm and take appropriate remedial actions. Buyer will fully indemnify TI and its representatives against any damages arising out of the use of any TI components in safety-critical applications.

In some cases, TI components may be promoted specifically to facilitate safety-related applications. With such components, TI's goal is to help enable customers to design and create their own end-product solutions that meet applicable functional safety standards and requirements. Nonetheless, such components are subject to these terms.

No TI components are authorized for use in FDA Class III (or similar life-critical medical equipment) unless authorized officers of the parties have executed a special agreement specifically governing such use.

Only those TI components which TI has specifically designated as military grade or "enhanced plastic" are designed and intended for use in military/aerospace applications or environments. Buyer acknowledges and agrees that any military or aerospace use of TI components which have *not* been so designated is solely at the Buyer's risk, and that Buyer is solely responsible for compliance with all legal and regulatory requirements in connection with such use.

TI has specifically designated certain components as meeting ISO/TS16949 requirements, mainly for automotive use. In any case of use of non-designated products, TI will not be responsible for any failure to meet ISO/TS16949.

#### Products Applications

Audio www.ti.com/audio Automotive and Transportation www.ti.com/automotive **Amplifiers** amplifier.ti.com Communications and Telecom www.ti.com/communications **Data Converters** dataconverter.ti.com Computers and Peripherals www.ti.com/computers **DLP® Products** www.dlp.com Consumer Electronics www.ti.com/consumer-apps DSP dsp.ti.com **Energy and Lighting** www.ti.com/energy Clocks and Timers www.ti.com/clocks Industrial www.ti.com/industrial Interface interface.ti.com Medical www.ti.com/medical Logic Security www.ti.com/security logic.ti.com

Power Mgmt power.ti.com Space, Avionics and Defense www.ti.com/space-avionics-defense

Microcontrollers microcontroller.ti.com Video and Imaging www.ti.com/video

RFID www.ti-rfid.com

OMAP Applications Processors www.ti.com/omap TI E2E Community e2e.ti.com

Wireless Connectivity www.ti.com/wirelessconnectivity